## NSN 5961-00-421-9151



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-421-9151 **Inclosure Material:** Metal **Overall Length:** Between 0.780 inches and 0.800 inches **Terminal Length:** 1.500 inches **Overall Height:** 0.260 inches **Overall Width:** 0.390 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method:** Unthreaded hole **Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 350.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 20.00 microamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** No

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